## TOSHIBA

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC7SZ08F, TC7SZ08FU

### **2 INPUT AND GATE**

#### **FEATURES**

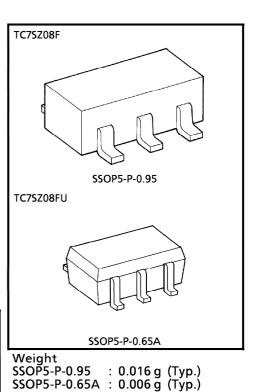
- High Output Drive : ±24 mA (Typ.)
- Super High Speed Operation : tpD = 2.7 ns (Typ.)
  - $(V_{CC} = 5 V, 50 pF)$

 $(V_{CC} = 3 V)$ 

- : V<sub>CC</sub> (opr) = 1.8~5.5 V **Operation Voltage Range**
- Supply Voltage Data Retention :  $V_{CC} = 1.5 \sim 5.5 V$
- **5 V Toleratnt Function**
- Matches the Performance of TC74LCX Series when Operated at 3.3 V V<sub>CC</sub>

#### MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC                     | SYMBOL           | RATING   | UNIT |
|------------------------------------|------------------|----------|------|
| Supply Voltage Range               | Vcc              | -0.5~6   | V    |
| DC Input Voltage                   | VIN              | -0.5~6   | V    |
| DC Output Voltage                  | Vout             | -0.5~6   | V    |
| Input Diode Current                | ЧК               | ± 20     | mA   |
| Output Diode Current               | ΙΟΚ              | ± 20     | mA   |
| DC Output Current                  | Ιουτ             | ± 50     | mA   |
| DC V <sub>CC</sub> /Ground Current | lcc              | ± 50     | mA   |
| Power Dissipation                  | PD               | 200      | mW   |
| Storage Temperature                | T <sub>stg</sub> | - 65~150 | °C   |
| Lead Temperature (10 s)            | Т                | 260      | °C   |



#### 980910FBA1

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### DC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC SYMBOL        |          | TEST CONDITION                              |                           | 1/          | - Ta = 25°C               |      | °C                        | $Ta = -40 \sim 85^{\circ}C$ |                           | UNIT |
|------------------------------|----------|---|---------------------------|-------------|---------------------------|------|---------------------------|-----------------------------|---------------------------|------|
| CHARACTERISTIC               | STIVIDUL | 1531  | CONDITION                 | Vcc<br>(V)  | MIN.                      | TYP. | MAX.                      | MIN.                        | MAX.                      |      |
| High-Level                   |          |   |                           | 1.8         | 0.88<br>× V <sub>CC</sub> |      | _                         | 0.88<br>× V <sub>CC</sub>   | _                         | v    |
| Input Voltage                | VIH      |   |                           | 2.3~<br>5.5 | 0.75<br>× V <sub>CC</sub> | _    | -                         | 0.75<br>× V <sub>CC</sub>   | -                         |      |
| Low-Level                    | Vu       |   |                           | 1.8         | _                         |      | 0.12<br>× V <sub>CC</sub> | _                           | 0.12<br>× V <sub>CC</sub> | v    |
| Input Voltage                | VIL      |   | _                         | 2.3~<br>5.5 | _                         | —    | 0.25<br>× V <sub>CC</sub> | _                           | 0.25<br>× V <sub>CC</sub> | Ŭ    |
|                              |          |   |                           | 1.8         | 1.7                       | 1.8  |                           | 1.7                         | _                         |      |
|                              |          |   | $I_{OH} = -100 \mu A$     | 2.3         | 2.2                       | 2.3  |                           | 2.2                         | _                         |      |
|                              |          |   |                           | 3.0         | 2.9                       | 3.0  |                           | 2.9                         | _                         |      |
| High-Level                   | ∨он      | V <sub>IN</sub> = V <sub>IH</sub>           |                           | 4.5         | 4.4                       | 4.5  |                           | 4.4                         | _                         | v    |
| Output Voltage               | ₩ОН      |   | 10H = -0 MA               | 2.3         | 1.9                       | 2.15 | _                         | 1.9                         | _                         |      |
|                              |          |   | I <sub>OH</sub> = -16 mA  | 3.0         | 2.4                       | 2.8  | _                         | 2.4                         | —                         |      |
|                              |          |   | $I_{OH} = -24  \text{mA}$ | 3.0         | 2.3                       | 2.68 |                           | 2.3                         |                           |      |
|                              |          |   | $I_{OH} = -32 \text{ mA}$ | 4.5         | 3.8                       | 4.2  | _                         | 3.8                         | _                         |      |
|                              |          |   | l <sub>OL</sub> = 100 μA  | 1.8         | _                         | 0    | 0.1                       | —                           | 0.1                       | v    |
|                              |          |   |                           | 2.3         | _                         | 0    | 0.1                       | —                           | 0.1                       |      |
|                              |          |   |                           | 3.0         | _                         | 0    | 0.1                       | —                           | 0.1                       |      |
| Low-Level                    | Val      | $V_{IN} = V_{IH}$                           |                           | 4.5         | _                         | 0    | 0.1                       | _                           | 0.1                       |      |
| Output Voltage               | VOL      | or V <sub>IL</sub>                          | l <sub>OL</sub> = 8 mA    | 2.3         | _                         | 0.1  | 0.3                       | _                           | 0.3                       |      |
|                              |          |   | l <sub>OL</sub> = 16 mA   | 3.0         | _                         | 0.15 | 0.4                       | —                           | 0.4                       | -    |
|                              |          |   | l <sub>OL</sub> = 24 mA   | 3.0         | _                         | 0.22 | 0.55                      | _                           | 0.55                      |      |
|                              |          |   | l <sub>OL</sub> = 32 mA   | 4.5         | —                         | 0.22 | 0.55                      | —                           | 0.55                      |      |
| Input Leakage<br>Current     | IIN      | V <sub>IN</sub> = 5.5 \                     | / or GND                  | 0~<br>5.5   | _                         | _    | ±1                        | _                           | ± 10                      | μΑ   |
| Power Off<br>Leakage Current | IOFF     | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V |                           | 0.0         | _                         | _    | 1                         | _                           | 10                        | μΑ   |
| Quiescent<br>Supply Current  | lcc      | V <sub>IN</sub> = V <sub>CC</sub>           | or GND                    | 5.5         |                           |      | 2                         | _                           | 20                        | μΑ   |

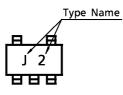
|   | SYMBOL TEST CONDITION   |                          |                     | Ta = 25°C |      | $Ta = -40 \sim 85^{\circ}C$ |      | UNIT |            |
|---|-------------------------|--------------------------|---------------------|-----------|------|-----------------------------|------|------|------------|
| CHARACTERISTIC  | CHARACTERISTIC SYMBOL   | V <sub>CC</sub> (V)      | V <sub>CC</sub> (V) | MIN.      | TYP. | MAX.                        | MIN. | MAX. |            |
|   |                         | 1.8                      | 2.0                 | 5.2       | 10.0 | 2.0                         | 10.5 |      |            |
| Propagation t <sub>PLH</sub><br>Delay Time t <sub>PHL</sub> | C <sub>L</sub> = 15 pF, | 2.5 ± 0.2                | 0.8                 | 3.4       | 7.0  | 0.8                         | 7.5  |      |            |
|   | $R_L = 1 M \Omega$      | 3.3 ± 0.3                | 0.5                 | 2.6       | 4.7  | 0.5                         | 5.0  |      |            |
|   |                         |                          | 5.0 ± 0.5           | 0.5       | 2.2  | 4.1                         | 0.5  | 4.4  | ns         |
|   |                         | C <sub>L</sub> = 50 pF,  | 3.3 ± 0.3           | 1.5       | 3.3  | 5.2                         | 1.5  | 5.5  |            |
|   |                         | $R_L = 500 \Omega$       | 5.0 ± 0.5           | 0.8       | 2.7  | 4.5                         | 0.8  | 4.8  |            |
| Input Capacitance   | C <sub>IN</sub>         |                          | 0~5.5               | _         | 4    | —                           | _    | _    | рF         |
| Power Dissipation<br>Capacitance                            | ion (Note :             | (Neta 1)                 | 3.3                 | —         | 20   | —                           | —    |      | <b>۳</b> ۲ |
|   | ЧРD                     | C <sub>PD</sub> (Note 1) | 5.5                 | _         | 25   | _                           | _    |      | рF         |

#### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3 \text{ ns}$ )

(Note 1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

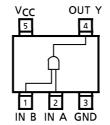
MARKING



#### TRUTH TABLE

| А | В | Y |
|---|---|---|
| L | L | L |
| L | Н | L |
| Н | L | L |
| Н | Н | Н |

#### PIN ASSIGNMENT (TOP VIEW)

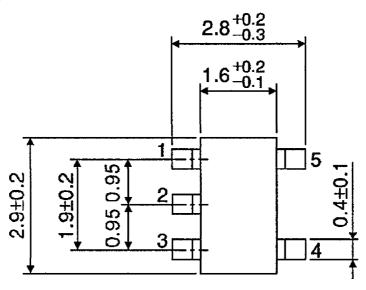


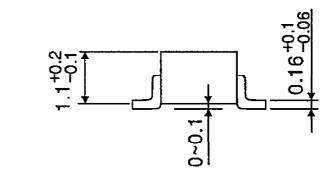
#### LOGIC DIAGRAM

| IN A<br>IN B | & | OUT Y |
|--------------|---|-------|
|--------------|---|-------|

OUTLINE DRAWING SSOP5-P-0.95

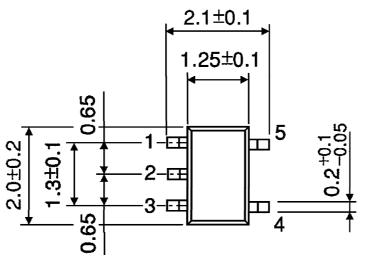
Unit : mm

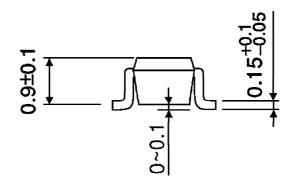




Weight: 0.016 g (Typ.)

OUTLINE DRAWING SSOP5-P-0.65A





Weight: 0.006 g (Typ.)

Unit : mm

### Tape Packing Specifications for 5-pin Ultra Super-Mini (USV) Package

#### Scope

This specification provides the packaging requirements for 5-pin Ultra Super Mini type transistors, FETs, diodes, L-MOS logics for use in automatic placement machines.

#### 1. Product Naming System

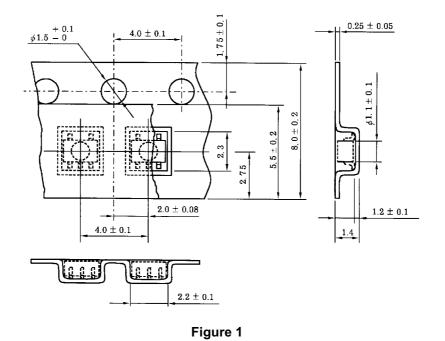
Type of package for shipment is classified by a symbol suffixed to a product name. The method of classification is as below. (this method, however, does not apply to products of which electrical characteristics differ from the TOSHIBA standard specifications.)

[Example]

| TC7S00FU | (TE85L) |                                    |
|----------|---------|------------------------------------|
|          |         | Indicates the specifications.      |
|          |         | Indicates EIAJ registration No. or |
|          |         | TOSHIBA's House No.                |

#### 2. Tape Dimensions

- 2.1 Accumulated pitch tolerance is ±0.2 mm/10 pitch.
- 2.2 The tape material is plastic.
- 2.3 The tape dimensions are per Figure 1.



961001EAA1

Unit: mm

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#### 2.4 Related Matters

#### 2.4.1 Missing Devices

Except for the leader and trailer portions of the tape there shall be no consecutive missing parts. The maximum number of missing parts cannot exceed 0.2% per reel.

#### 2.4.2 Electric Characteristics

Electric Characteristics of taping devices are shown in individual Technical Data.

#### 3. Reel

#### 3.1 The reel dimensions are per Figure 2.

Unit: mm

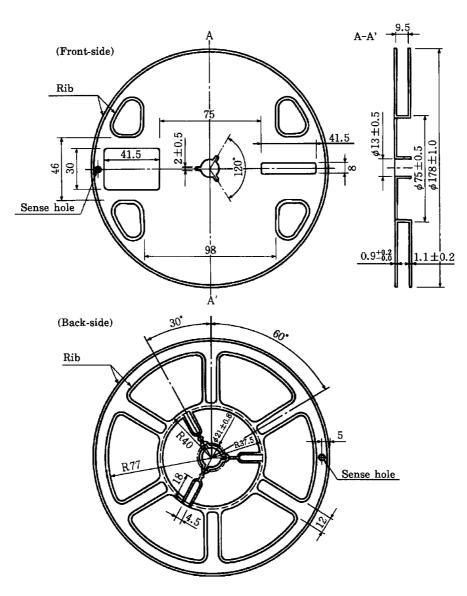


Figure 2

3.2 The reel material is plastic.

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#### 4. Packed System

#### 4.1 Packed parts quantity

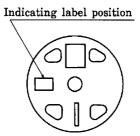
3000 pcs per reel.

#### 4.2 Indication System

[Example] TC7S00FU (TE85L)

#### P/N:

| TYPE | TC7S00FU |      |           |
|------|----------|------|-----------|
| ADDC | (TE85L)  | Q'TY | 3,000 pcs |
| NOTE |          |      |           |



On special occasion ADD CODE, PART No. etc. are often indicated in indicating label of the reel.

#### 4.3 Part orientation in the carrier tape shall be as shown in Figure 3.

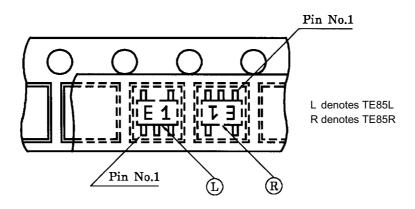
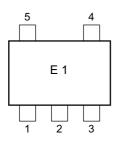


Figure 3

Pin 1 exists on the left below of the marking.

[Example] Top View



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  - 5. The leader and trailer portion of the tape shall be as shown in Figure 4.

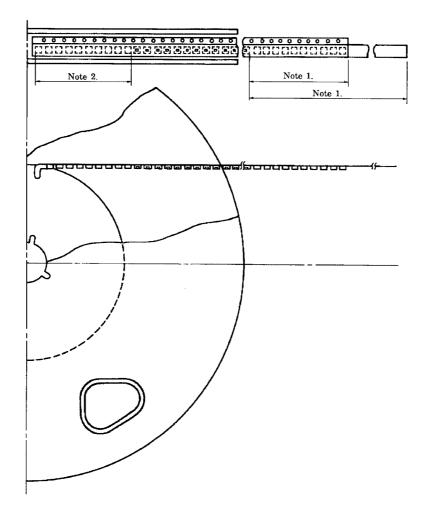


Figure 4

- Note1: The leader portion shall consist of a piece of cover tape minimum length of 300 mm and a piece of carrier tape with empty portion of 100 mm minimum.
- Note2: The trailer portion shall consist of an empty carrier of more than 10 cavities.